

# **Bipolar Transistor**

# (-)50 V, (-)3 A, Low V<sub>CE(sat)</sub>, (PNP)NPN Single CPH6

# CPH6123, CPH6223

#### **Features**

- Adoption of MBIT Process
- Large Current Capacity
- Low Collector-to-Emitter Saturation Voltage
- High-Speed Switching
- Ultrasmall Package Facilitates Miniaturization in End Products (Mounting Height: 0.9 mm)
- High Allowable Power Dissipation
- These are Pb-Free Devices

#### **Applications**

 DC-DC Converters, Relay Drivers, Lamp Drivers, Motor Drivers, Strobe

### **ABSOLUTE MAXIMUM RATINGS** (at T<sub>A</sub> = 25°C)

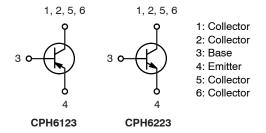
Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CBO</sub>	Collector-to-Base Voltage		(-50)100	V
V <sub>CES</sub>	Collector-to- Emitter Voltage		(-50)100	V
V <sub>CEO</sub>	Collector-to- Emitter Voltage		(-)50	V
V <sub>EBO</sub>	Emitter-to-Base Voltage		(-)6	V
I <sub>C</sub>	Collector Current		(-)3	Α
I <sub>CP</sub>	Collector Current (Pulse)		(-)6	Α
Ι <sub>Β</sub>	Base Current		(-)600	mA
P <sub>C</sub>	Collector Dissipation	When mounted on ceramic substrate (600 mm <sup>2</sup> × 0.8 mm)	1.3	W
Tj	Junction Temperature		150	°C
T <sub>stg</sub>	Storage Temperature		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

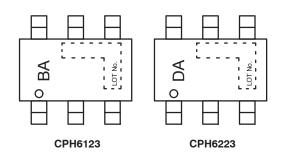


CPH6 CASE 318BD

#### **ELECTRICAL CONNECTION**



# **MARKING DIAGRAMS**



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
CPH6123-TL-E	CPH6 (Pb-Free)	3 000 / Tape & Reel
CPH6223-TL-E	CPH6 (Pb-Free)	3 000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, <a href="https://example.com/br/>BRD8011/D">BRD8011/D</a>.

# **ELECTRICAL CHARACTERISTICS** (at T<sub>A</sub> = 25°C)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = (-)40 V, I <sub>E</sub> = 0 A			(–)1	μΑ
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = (-)4 V, I <sub>C</sub> = 0 A			(–)1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = (-)2 \text{ V}, I_{C} = (-)100 \text{ mA}$	200		560	
$f_{T}$	Gain-Bandwidth Product	$V_{CE} = (-)10 \text{ V}, I_{C} = (-)500 \text{ mA}$		(390) 380		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = (-)10 V, f = 1 MHz		(24) 13		pF
V <sub>CE</sub> (sat)1	Collector-to-Emitter Saturation	I <sub>C</sub> = (-)1 A, I <sub>B</sub> = (-)50 mA		(-115) 90	(-230) 130	mV
V <sub>CE</sub> (sat)2	Voltage	I <sub>C</sub> = (-)2 A, I <sub>B</sub> = (-) 100 mA		(-240) 160	(-650) 240	mV
V <sub>BE</sub> (sat)	Base-to-Emitter Saturation Voltage	I <sub>C</sub> = (-)2 A, I <sub>B</sub> = (-)100 mA		(-)0.88	(-)1.2	V
V <sub>(BR)CBO</sub>	Collector-to-Base Breakdown Voltage	$I_C = (-)10 \mu A, I_E = 0 A$	(-50) 100			V
V <sub>(BR)CES</sub>	Collector-to-Emitter Breakdown Voltage	$I_C$ = (-)100 $\mu$ A, $R_{BE}$ = 0 $\Omega$	(-50) 100			V
V <sub>(BR)CEO</sub>	Collector-to-Emitter Breakdown Voltage	$I_C$ = (-)1 mA, $R_{BE}$ = $\infty$	(–)50			V
V <sub>(BR)EBO</sub>	Emitter-to-Base Breakdown Voltage	$I_E = (-)10 \mu A, I_C = 0 A$	(-)6			V
t <sub>on</sub>	Turn-On Time	See specified Test Circuit.		(30) 35		ns
t <sub>stg</sub>	Storage Time			(230) 300		ns
t <sub>f</sub>	Fall Time			(18) 25		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

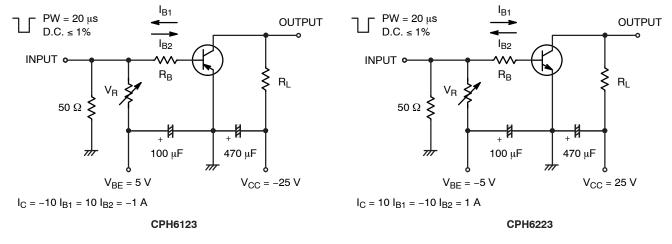
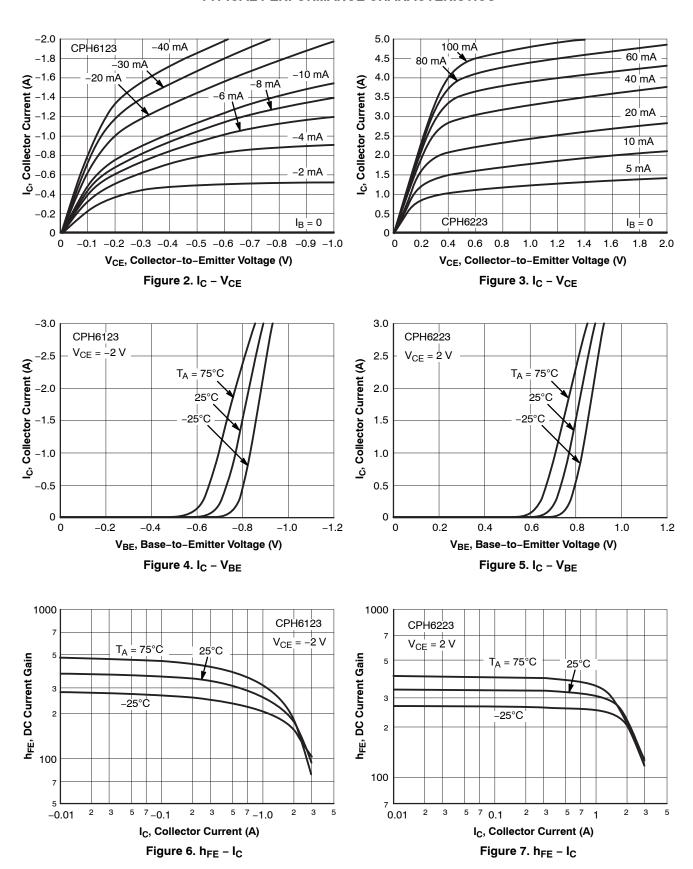
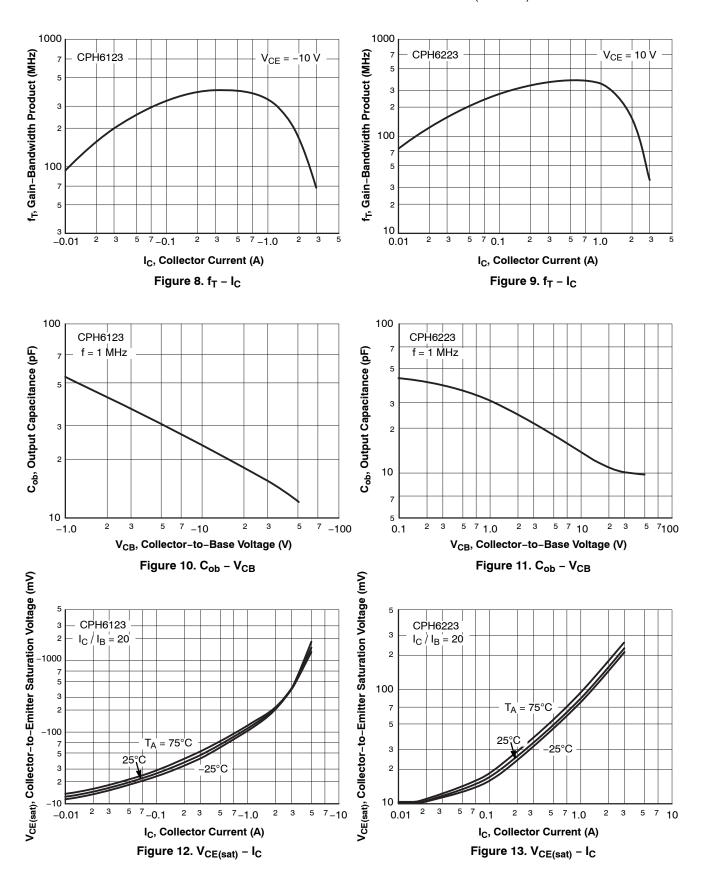


Figure 1. Switching Time Test Circuit

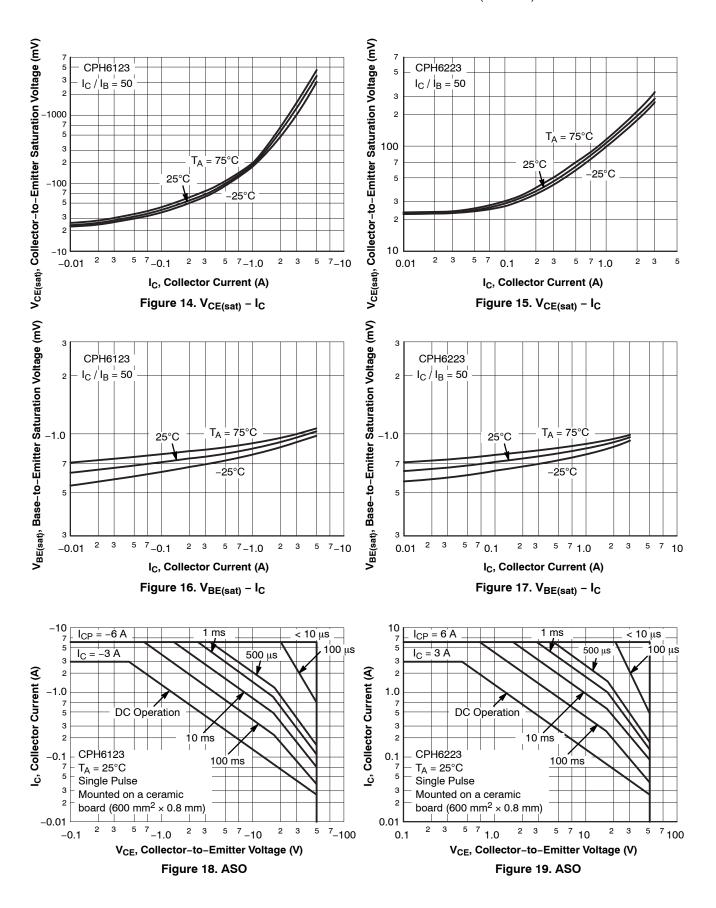
#### TYPICAL PERFORMANCE CHARACTERISTICS



# TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



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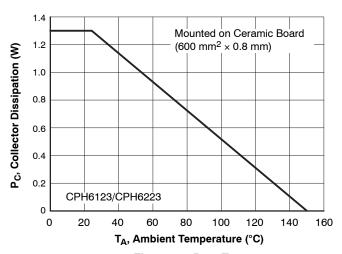
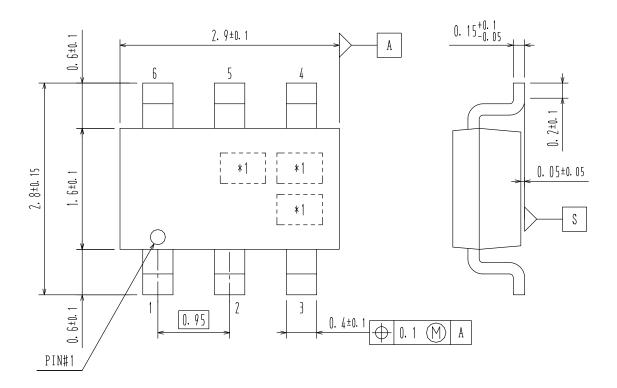
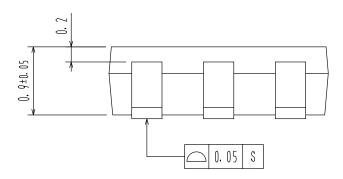


Figure 20. P<sub>C</sub> - T<sub>A</sub>

CPH6 CASE 318BD ISSUE O

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